EPISTAR

ES-SADOPN14R

AlGalnAs PN-series LED Chip

> Mechanical Specification:

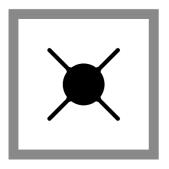
(1) Dimension

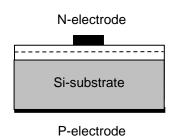
- Chip size: 14 mil x 14 mil (363±25 μm x 363±25 μm)

- Thickness: 6.7 mil (170±25 μ m) - N bonding pad: 3.9 mil (100±10 μ m)

(2) Metallization

Topside N electrode : Au alloyBackside P electrode: Au alloy





Features:

- · High radiant flux
- · Thin film structure
- · Vertical electrode
- · High driving current

Applications:

- Sensing system
- Medical appliances
- Wafer inspection

> Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward Voltage	Vf1		If = 10μA	0.3	-	-	V
	Vf2		If = 100mA	-	1.1	1.5	V
Reverse Current	Ir		Vr = 5V	-	-	5.0	μΑ
Peak Wavelength ⁽¹⁾	λр		If = 100mA	1250	1300	1350	nm
Spectra Half-width	Δλ		If = 100mA	-	83	-	nm
Radiant flux ⁽²⁾⁽³⁾	Ро	E11	If = 100mA	13	-	-	mW
		E12		15	-	-	
		E13		18	-	-	

Note:

⁽¹⁾ Basically, the wavelength span is 100nm; however, customers' special requirements are also welcome.

⁽²⁾ Customers' special requirements are also welcome.

⁽³⁾ Radiant flux is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 150	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 5	V
Junction Temperature	Tj	-	≤ 115	°C
		Chip	-40 ~ +85	°C
Storage Temperature	Tstg	Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MCPCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 – Relative Radiant Flux vs. Forward Current

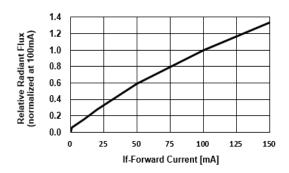


Fig.3 – Relative Radiant Flux (@100mA) vs. Ambient Temperature

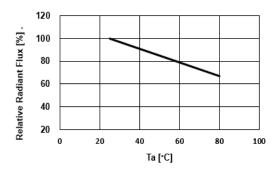


Fig.5 – Peak Wavelength (@100mA) vs. Ambient Temperature

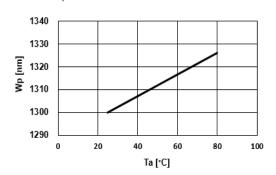


Fig.2 – Forward Current vs. Forward Voltage

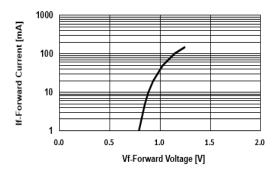


Fig.4 – Forward Voltage (@100mA) vs. Ambient Temperature

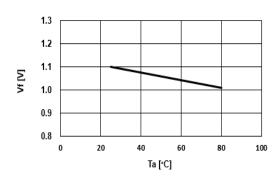


Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 115°C)

